



ZXMN3A01F

30V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| V _{(BR)DSS} | R _{DS(ON)} | I _D T _A = +25°C |
|----------------------|-----------------------------|--|
| 30V | $0.12\Omega @ V_{GS} = 10V$ | 2.0A |

Description

This new generation MOSFET has been designed to minimize the onstate resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Power Management Functions
- Motor Control

Features

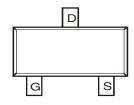
- Low On-Resistance
- Fast Switching Speed
- Low Threshold
- Low Gate Drive
- Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

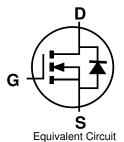
- Case: SOT23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Solderable per MIL-STD-202, Method 208 (3)
- Lead Free Plating (Matte Tin Finish Annealed over Alloy 42 Leadframe)
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)



Top View



Top View Pin Configuration



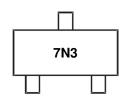
Ordering Information (Note 4)

| Part Number | Case | Packaging |
|-------------|-------|--------------------|
| ZXMN3A01FTA | SOT23 | 3,000/Tape & Reel |
| ZXMN3A01FTC | SOT23 | 10,000/Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



7N3 = Product Type Marking Code



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

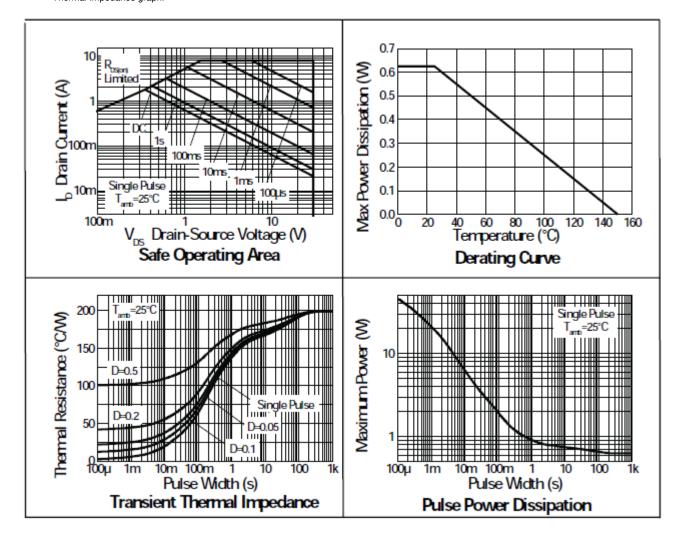
| Characteristic | Symbol | Value | Units | | |
|---|----------------------------------|--|-----------------|-------------------|---|
| Drain-Source Voltage | V_{DSS} | 30 | V | | |
| Gate-Source Voltage | V _{GSS} | ±20 | V | | |
| Continuous Drain Current, V _{GS} = 10V | (Note 6) (Note 6) (Note 5) | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ $T_A = +25^{\circ}C$ | I _D | 2.0 1.6 1.8 | А |
| Pulsed Drain Current (Note 7) | | | I _{DM} | 8 | Α |
| Maximum Body Diode Continuous Current (Note 6) | I _S | 1.3 | А | | |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Units |
|---|----------------------|----------------------------------|-------------|-------------|
| Total Power Dissipation Linear Derating Factor | (Note 5) | P _D | 625 5 | mW mW/°C |
| Total Power Dissipation Linear Derating Factor | (Note 6) | P _D | 806 6.4 | mW mW/°C |
| Thermal Resistance, Junction to Ambient | (Note 5) (Note 6) | $R_{	heta JA}$ | 200 155 | °C/W |
| Operating and Storage Temperature Range | | T _{J,} T _{STG} | -55 to +150 | °C |

Notes:

- 5. For a device surface mounted on 25mm x 25mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions.
- 6. For a device surface mounted on FR-4 PCB measured at t≤5 secs.
- 7. Repetitive rating 25mm x 25mm FR-4 PCB, D = 0.05, pulse width 10µs pulse width limited by maximum junction temperature. Refer to Transient Thermal Impedance graph.





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

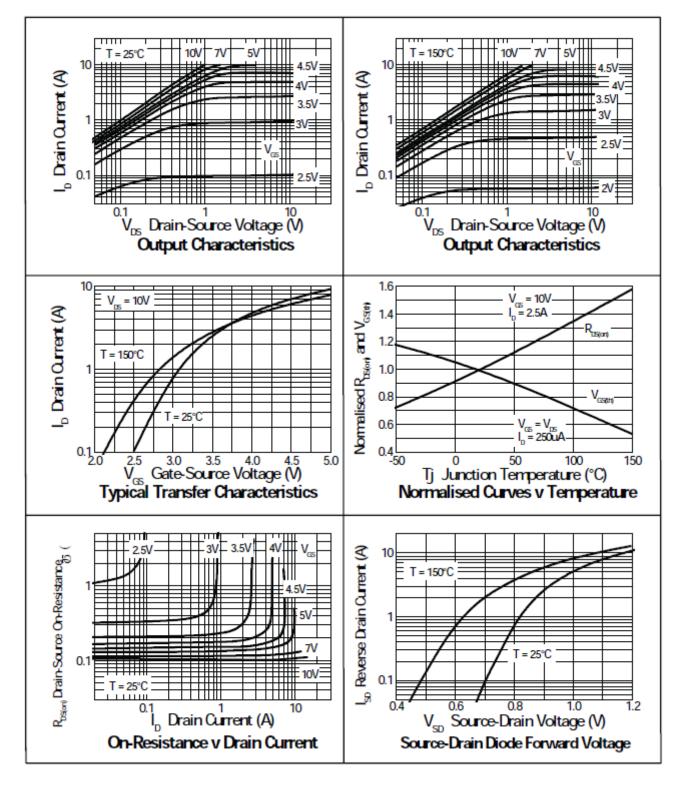
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-----|------|------|------|--|--|
| OFF CHARACTERISTICS | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 30 | _ | _ | V | $V_{GS} = 0V, I_D = 250\mu A$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | _ | 0.5 | μΑ | $V_{DS} = 30V, V_{GS} = 0V$ | |
| Gate-Body Leakage | Igss | _ | _ | 100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS | | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | 1 | _ | 2.5 | V | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | |
| Static Drain-Source On-Resistance (Note 8) | | | 0.11 | 0.12 | Ω | $V_{GS} = 10V, I_D = 2.5A$ | |
| Static Drain-Source On-Nesistance (Note o) | R _{DS(ON)} | | _ | 0.18 | Ω | $V_{GS} = 4.5V, I_D = 2A$ | |
| Forward Transconductance | g FS | | 3.5 | _ | S | $V_{DS} = 4.5V, I_D = 2.5A$ | |
| Diode Forward Voltage (Note 8 & 10) | V_{SD} | _ | 0.85 | 0.95 | V | $V_{GS} = 0V$, $I_S = 1.7A$, $T_J = +25$ °C | |
| DYNAMIC CHARACTERISTICS (Note 10) | | | | | | | |
| Input Capacitance | C _{iss} | _ | 190 | _ | | V _{DS} = 25V, V _{GS} = 0V, f = 1MHz | |
| Output Capacitance | Coss | _ | 38 | | pF | | |
| Reverse Transfer Capacitance | Crss | _ | 20 | | | 1 - 1101112 | |
| Gate Charge (Note 9) | Q_g | | 2.3 | _ | | $V_{DS} = 15V$, $V_{GS} = 5V$, $I_{D} = 2.5A$ | |
| Total Gate Charge (Note 9) | Q_g | _ | 3.9 | _ | nC | V _{DS} = 15V, V _{GS} = 10V, I _D = 2.5A | |
| Gate-Source Charge (Note 9) | Q_{gs} | | 0.6 | _ | 110 | | |
| Gate-Drain Charge (Note 9) | Q_{gd} | _ | 0.9 | _ | | | |
| Turn-On Delay Time (Note 9) | t _{D(on)} | _ | 1.7 | _ | | $V_{DD} = 15V$, $I_D = 2.5A$, $R_G = 6\Omega$, $V_{GS} = 10V$ | |
| Turn-On Rise Time (Note 9) | t _r | _ | 2.3 | _ | | | |
| Turn-Off Delay Time (Note 9) | t _{D(off)} | _ | 6.6 | _ | ns | | |
| Turn-Off Fall Time (Note 9) | t _f | _ | 2.9 | _ | | | |
| Reverse Recovery Time | t _{rr} | _ | 17.7 | _ | ns | T. 125°C I. 2.5A di/dt 100A/15 | |
| Reverse Recovery Charge | Qrr | _ | 13 | _ | nC | $T_J = +25$ °C, $I_F = 2.5$ A, $di/dt = 100$ A/ μ s | |

Notes:

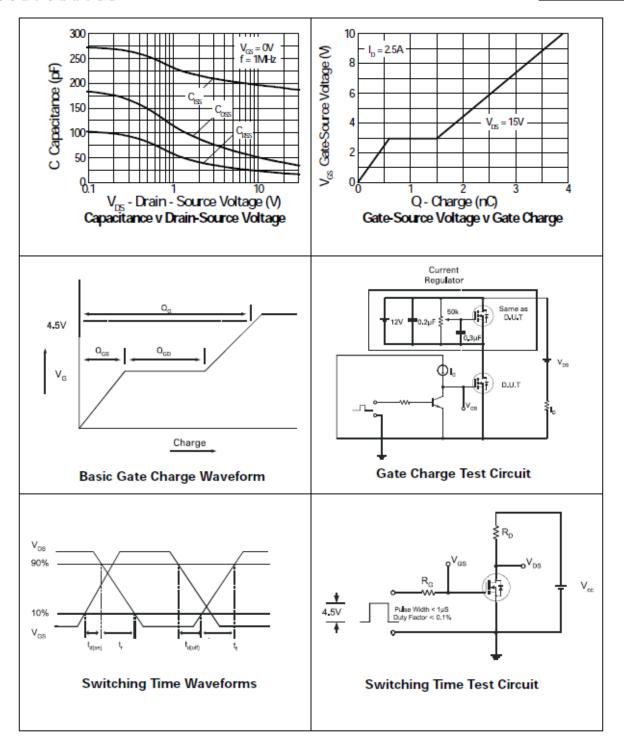
- 8. Measured under pulsed conditions. Width=300µs. Duty cycle \leq 2%.
- 9. Switching characteristics are independent of operating junction temperature.

 10. Guaranteed by design. Not subject to production testing.





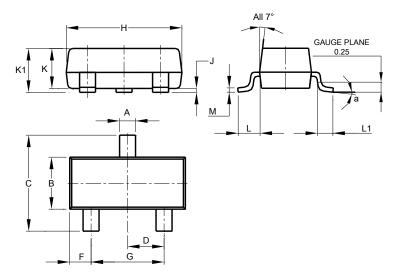






Package Outline Dimensions

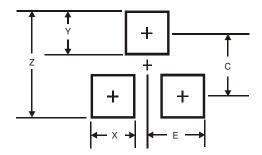
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| SOT23 | | | | | | |
|-------|----------------------|-------|-------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.37 | 0.51 | 0.40 | | | |
| В | 1.20 | 1.40 | 1.30 | | | |
| С | 2.30 | 2.50 | 2.40 | | | |
| D | 0.89 | 1.03 | 0.915 | | | |
| F | 0.45 | 0.60 | 0.535 | | | |
| G | 1.78 | 2.05 | 1.83 | | | |
| Н | 2.80 | 3.00 | 2.90 | | | |
| J | 0.013 | 0.10 | 0.05 | | | |
| K | 0.890 | 1.00 | 0.975 | | | |
| K1 | 0.903 | 1.10 | 1.025 | | | |
| L | 0.45 | 0.61 | 0.55 | | | |
| L1 | 0.25 | 0.55 | 0.40 | | | |
| М | 0.085 | 0.150 | 0.110 | | | |
| а | 8° | | | | | |
| All | All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) | | | | |
|------------|---------------|--|--|--|--|
| Z | 2.9 | | | | |
| Х | 0.8 | | | | |
| Υ | 0.9 | | | | |
| С | 2.0 | | | | |
| E | 1.35 | | | | |



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